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Vishay General Semiconductor

## Surface Mount Trench MOS Barrier Schottky Rectifiers



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#### DESIGN SUPPORT TOOLS



| PRIMARY CHARACTERISTICS                |                |  |  |  |  |  |  |
|--|----------------|--|--|--|--|--|--|
| I <sub>F(AV)</sub>                     | 1.0 A          |  |  |  |  |  |  |
| V <sub>RRM</sub>                       | 120 V          |  |  |  |  |  |  |
| I <sub>FSM</sub>                       | 30 A           |  |  |  |  |  |  |
| $V_F$ at $I_F$ = 1 A ( $T_A$ = 125 °C) | 0.61 V         |  |  |  |  |  |  |
| T <sub>J</sub> max.                    | 175 °C         |  |  |  |  |  |  |
| Package                                | SMF (DO-219AB) |  |  |  |  |  |  |
| Circuit configuration                  | Single         |  |  |  |  |  |  |

### FEATURES

- Trench MOS Schottky technology
- Low profile package
- Ideal for automated placement
- Low forward voltage drop, low power losses
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Wave and reflow solderable
- AEC-Q101 qualified available
  Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency inverters, freewheeling, DC/DC converters, and polarity protection in commercial, industrial, and automotive applications.

### **MECHANICAL DATA**

**Case:** SMF (DO-219AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)             |                                   |             |         |  |  |  |  |
|--|-----------------------------------|-------------|---------|--|--|--|--|
| PARAMETER  | SYMBOL                            | V1FM12      | UNIT    |  |  |  |  |
| Device marking code  |                                   | 1MS         |         |  |  |  |  |
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>                  | 120         | V       |  |  |  |  |
| Maximum average forward rectified current (fig.1)                                  | I <sub>F(AV)</sub> <sup>(1)</sup> | 1.0         | A       |  |  |  |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I <sub>FSM</sub>                  | 30          | A       |  |  |  |  |
| Operating junction temperature range   | T <sub>J</sub> <sup>(2)</sup>     | -40 to +175 | <b></b> |  |  |  |  |
| Storage temperature range  | T <sub>STG</sub>                  | -55 to +175 | - C     |  |  |  |  |

#### Notes

<sup>(1)</sup> Free air, mounted on FR4 PCB, 2 oz. standard footprint

 $^{(2)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>0JA</sub>

Available

RoHS COMPLIANT HALOGEN FREE www.vishay.com

## V1FM12

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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                        |                           |                                 |      |      |      |  |  |
|---|------------------------|---------------------------|---------------------------------|------|------|------|--|--|
| PARAMETER   | TEST CONDITIONS        |                           | SYMBOL                          | TYP. | MAX. | UNIT |  |  |
| Instantaneous forward voltage   | I <sub>F</sub> = 0.5 A | T <sub>A</sub> = 25 °C    |                                 | 0.62 | -    | V    |  |  |
|   | I <sub>F</sub> = 1.0 A | $T_{A} = 25 \text{ C}$    |                                 | 0.77 | 0.87 |      |  |  |
|   | I <sub>F</sub> = 0.5 A | T 105 %C                  | VF()                            | 0.52 | -    |      |  |  |
|   | I <sub>F</sub> = 1.0 A | – T <sub>A</sub> = 125 °C |                                 | 0.61 | 0.69 |      |  |  |
|   | V <sub>R</sub> = 90 V  | T <sub>A</sub> = 25 °C    |                                 | 0.30 | -    |      |  |  |
| Reverse current   |                        | T <sub>A</sub> = 125 °C   | – I <sub>B</sub> <sup>(2)</sup> | 180  | -    |      |  |  |
| Reverse current   | V 100.V                | T <sub>A</sub> = 25 °C    | IR (-/                          | -    | 65   | μΑ   |  |  |
|   | V <sub>R</sub> = 120 V | T <sub>A</sub> = 125 °C   |                                 | 300  | 1500 |      |  |  |
| Typical junction capacitance  | 4.0 V, 1 MHz           |                           | CJ                              | 95   | -    | pF   |  |  |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: Pulse width  $\leq 5\mbox{ ms}$ 

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25$ °c unless otherwise noted) |                                 |        |      |  |  |  |
|--|---------------------------------|--------|------|--|--|--|
| PARAMETER  | SYMBOL                          | V1FM12 | UNIT |  |  |  |
| Typical thermal resistance   | R <sub>0JA</sub> (1)(2)         | 125    | °C/W |  |  |  |
| l'ypical thermal resistance  | R <sub>0JM</sub> <sup>(2)</sup> | 30     | 0/10 |  |  |  |

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

<sup>(2)</sup> Device mounted on FR4 PCB, 2 oz. standard footprint, thermal resistance  $R_{\theta JA}$  – junction-to-ambient; thermal resistance  $R_{\theta JM}$  – junction-to-mount

| ORDERING INFORMATION (Example) |                 |                        |               |                                    |  |  |  |  |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|--|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |  |  |  |  |
| V1FM12-M3/H                    | 0.015           | Н                      | 3000          | 7" diameter plastic tape and reel  |  |  |  |  |
| V1FM12-M3/I                    | 0.015           | I                      | 10 000        | 13" diameter plastic tape and reel |  |  |  |  |
| V1FM12HM3/H <sup>(1)</sup>     | 0.015           | Н                      | 3000          | 7" diameter plastic tape and reel  |  |  |  |  |
| V1FM12HM3/I <sup>(1)</sup>     | 0.015           | l                      | 10 000        | 13" diameter plastic tape and reel |  |  |  |  |

#### Note

(1) AEC-Q101 qualified



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## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

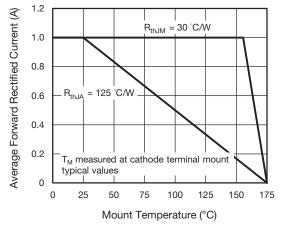


Fig. 1 - Maximum Forward Current Derating Curve

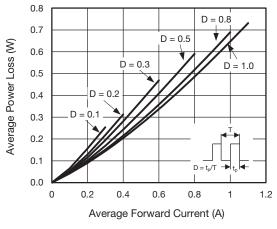


Fig. 2 - Average Power Loss Characteristics

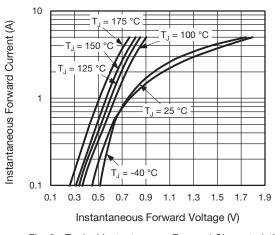


Fig. 3 - Typical Instantaneous Forward Characteristics

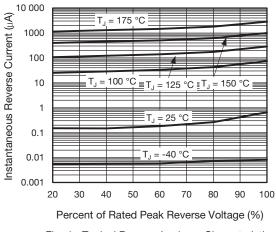
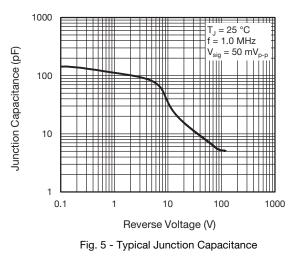


Fig. 4 - Typical Reverse Leakage Characteristics



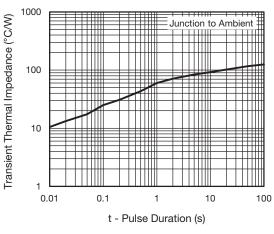


Fig. 6 - Typical Transient Thermal Impedance

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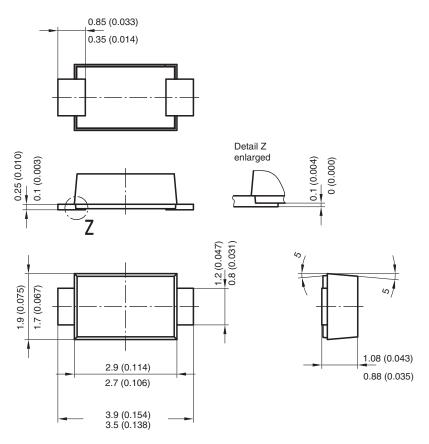
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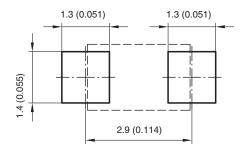


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### **PACKAGE OUTLINE DIMENSIONS** in millimeters (inches)



Foot print recommendation:

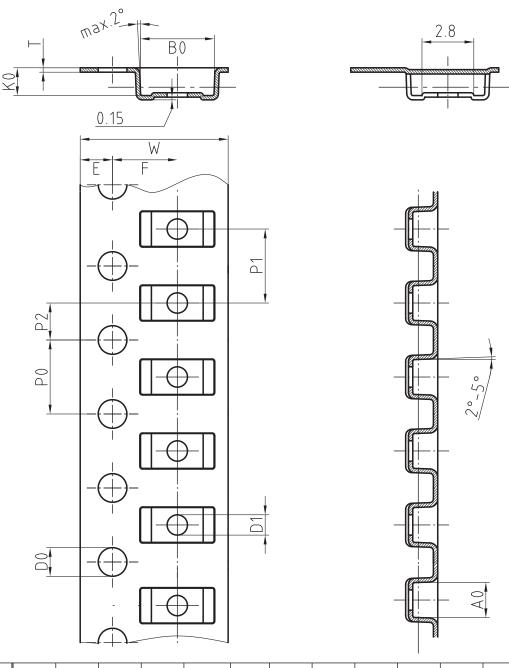


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### BLISTERTAPE DIMENSIONS in millimeters: SMF (DO-219AB)



| Mat: | A0  | B0  | K0  | W   | Т     | Ρ0  | P2  | P1  | D0  | D1 | E    | F   |
|------|-----|-----|-----|-----|-------|-----|-----|-----|-----|----|------|-----|
| PS   | 1.9 | 4.0 | 1.5 | 8.0 | 0.235 | 4.0 | 2.0 | 4.0 | 1.5 | 1  | 1.75 | 3.5 |

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